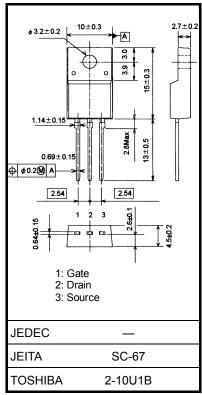
TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (π -MOSVI)

2SK3947

Switching Regulator Applications

- Low drain-source ON-resistance: R_{DS} (ON) = 1.1 Ω (typ.)
- High forward transfer admittance: |Y_{fs}| = 5.0S (typ.)
- Low leakage current: $I_{DSS} = 100 \ \mu A (V_{DS} = 600 \ V)$
- Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C) Symbol Unit Characteristic Rating Drain-source voltage VDSS 600 ۷ 600 v Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) VDGR V Gate-source voltage ±30 VGSS DC 6 (Note 1) I_D Drain current Α Pulse (t = 1 ms) 24 IDP (Note 1) w Drain power dissipation ($Tc = 25^{\circ}C$) P_D 40 Single-pulse avalanche energy EAS 345 mJ (Note 2) Avalanche current 6 А I_{AR} E_{AR} 4 Repetitive avalanche energy (Note 3) mJ °C Channel temperature T_{ch} 150 -55~150 °C Storage temperature range Tstg



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

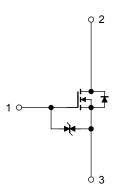
Characteristic	Symbol	Мах	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	3.125	°C/W	
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25 ^{\circ}C (initial), L = 16.8 mH, I_{AR} = 6 A, R_G = 25 Ω

Note 3: Repetitive rating: Pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



Unit: mm

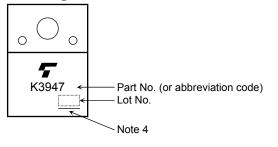
Electrical Characteristics (Ta = 25°C)

Char	acteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cui	rrent	I _{GSS}	$V_{GS}=\pm 25~V,~V_{DS}=0~V$		—	±10	μA
Gate-source brea	akdown voltage	V (BR) GSS	$I_G=\pm 10~\mu A,~V_{GS}=0~V$	±30	_		V
Drain cutoff curre	ent	IDSS	$V_{DS} = 600 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	_	100	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	600	_		V
Gate threshold v	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0	_	4.0	V
Drain-source ON	-resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$	_	1.1	1.4	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$	1.2	5.0		S
Input capacitance	e	C _{iss}			1050		
Reverse transfer capacitance		C _{rss}	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz		10		pF
Output capacitance		C _{oss}			110		
Switching time	Rise time	tr	V_{GS} $0 V$ V_{GS} $0 V$ V_{GS} $0 V$ 0	_	20		ns
	Turn-on time	t _{on}			40		
	Fall time	t _f		_	35	_	
	Turn-off time	t _{off}	Duty \leq 1%, t _w = 10 μ s	_	130	_	
Total gate charge Q		Qg		_	28	—	
Gate-source charge		Q _{gs}	$V_{DD} \simeq 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 6 \text{ A}$	_	16	—	nC
Gate-drain charge		Q _{gd}]	_	12		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	6	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_	_	24	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 6 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 6 \text{ A}, V_{GS} = 0 \text{ V},$	_	140	_	ns
Reverse recovery charge	Q _{rr}	dI _{DR} /dt = 100 A/μs	_	0.3	_	μC

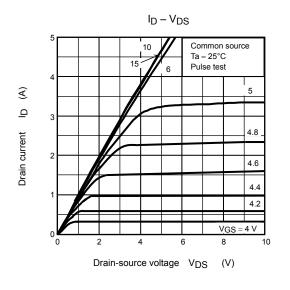
Marking

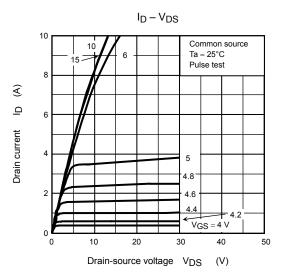


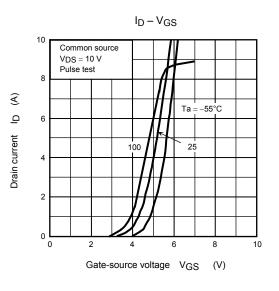
Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

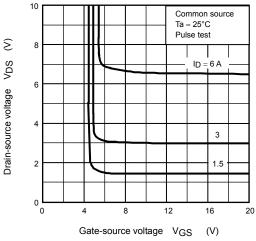
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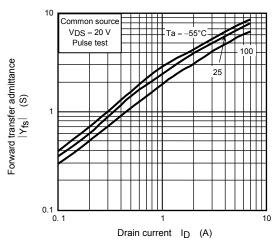




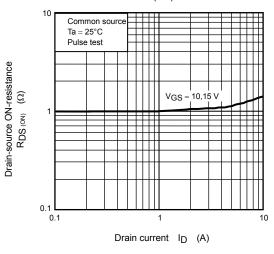


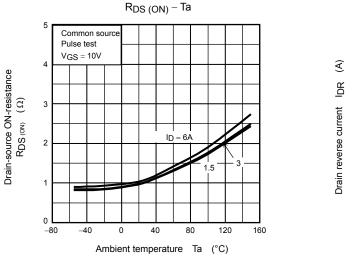


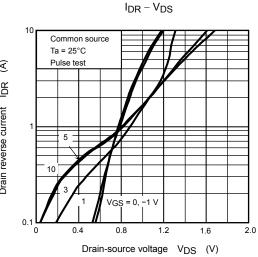




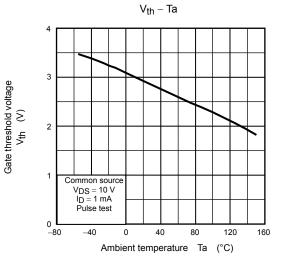
 $R_{DS(ON)} - I_D$

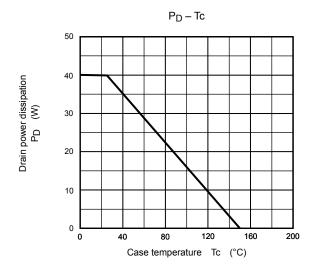




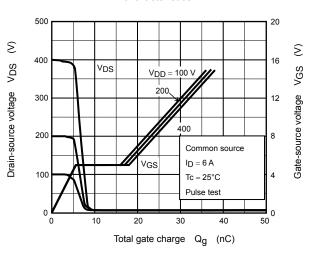


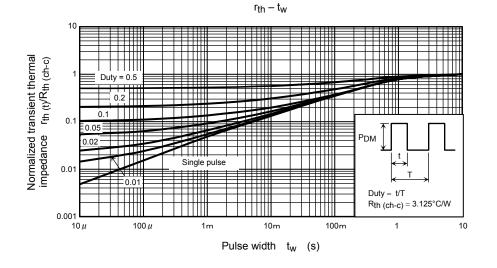
Capacitance - V_{DS} 10000 THE 1000 (PF) ပ Coss Capacitance 100 Ť Common source 10 VGS = 0 V f = 1 MHz Ta = 25°C 1 L 0.1 10 100 Drain-source voltage V_{DS} (V)

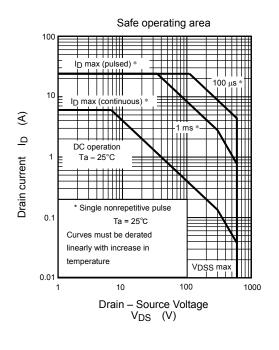


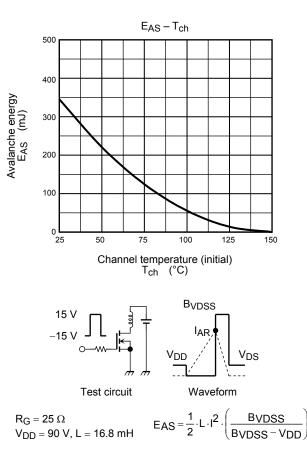


Dynamic input / output characteristics









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